NSN 5962-01-408-0816

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View Online at https://aerobasegroup.com/nsn/5962-01-408-0816

view Offiline at https://aerobasegroup.com/hist//3302-01-400-0010
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
F-16
Features Provided:
Burn in, mil-std-883, class b and monolithic and programmable and tested to mil-std-883
Inclosure Material:
Ceramic
Inclosure Configuration:
Pin grid array
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Current Rating Per Characteristic:
50.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Gold
Product Name:
Microcircuit, memory, digital, cmos 5000 gate programmable logic array, monolithic silicon
Voltage Rating And Type Per Characteristic:
0.4 volts low level output and 2.4 volts high level output and -0.5 volts power source and 7.0 volts power source
Capitance Rating Per Characteristic:
15.00 input picofarads and 15.00 output picofarads
Time Rating Per Chacteristic:
6.00 nanoseconds access
Memory Device Type:
Pal
Special Features:
Note: mrc ttqy-156 is number of pins used; case outline designator cmga8-pn as designated in mil-std-1835; device is a similar vendor
68994 xc4005-6pg156b which is a generic item 4005-6
Precious Material And Location:
Lead finish gold
Precious Material:
Gold
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
156 pin
Shelf Life:
N/a

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Unit Of Measure:

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Demilitarization:

No

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